

SANYO Semiconductors DATA SHEET

P-Channel Silicon MOSFET

VEC2302 — General-Purpose Switching Device **Applications**

Features

- The best suited for inverter applications.
- · Low ON-resistance.
- Composite type facilitating high-density mounting.
- · 4V drive.
- Mounting high 0.75mm.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-3	Α
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-12	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)1unit	0.9	W
Total Dissipation	PT	Mounted on a ceramic board (900mm ² X0.8mm)	1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0	-30			٧
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-30V, V _{GS} =0			-1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA	-1.0		-2.4	٧
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-1.5A	2.0	3.4		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-1.5A, VGS=-10V		65	86	mΩ
	R _{DS} (on)2	I _D =-0.7A, V _G S=-4V		117	168	mΩ
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		510		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		115		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-10V, f=1MHz		78		pF

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SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

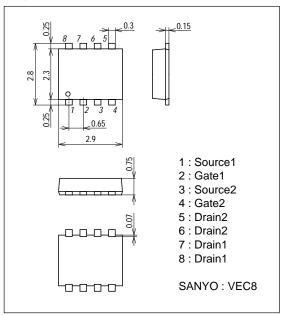
VEC2302

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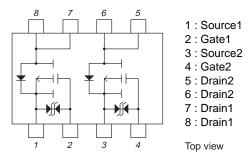
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		11		ns
Rise Time	tr	See specified Test Circuit		17		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		53		ns
Fall Time	tf	See specified Test Circuit		35		ns
Total Gate Charge	Qg	V _{DS} =-10V, V _{GS} =-10V, I _D =-3A		11		nC
Gate-to-Source Charge	Qgs	V _{DS} =-10V, V _{GS} =-10V, I _D =-3A		2.4		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-10V, V _{GS} =-10V, I _D =-3A		1.7		nC
Diode Forward Voltage	V _{SD}	I _S =-3A, V _{GS} =0		-0.87	-1.5	V

Package Dimensions

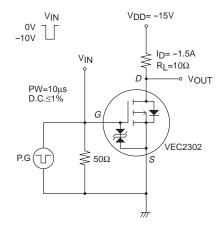
unit : mm 2227A

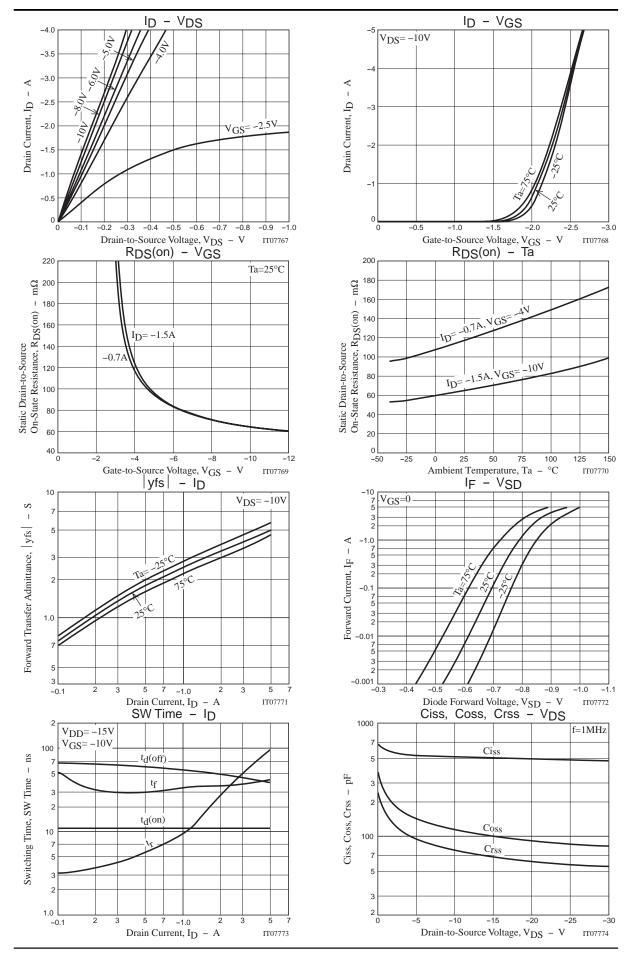


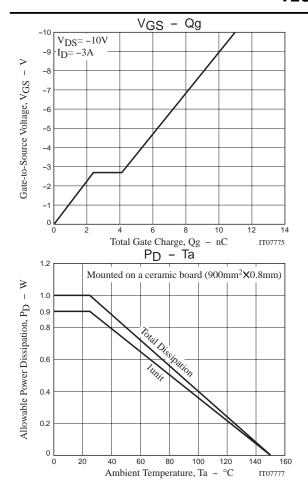
Electrical Connection

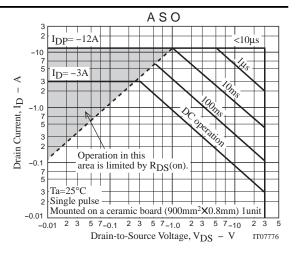


Switching Time Test Circuit









Note on usage: Since the VEC2302 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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